Diode Semiconductor Device - Page 1 of 1



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Ir	closure Material:
	lass
-	verall Length:
	265 inches
	erminal Length:
	000 inches
0	verall Diameter:
0	100 inches
J	bint Electronic Device Engineering Council/jedec/case Outline Designation:
	D-7
N	ounting Method:
Т	erminal
F	eatures Provided:
Н	ermetically sealed case
s	emiconductor Material:
s	licon
v	oltage Rating In Volts Per Characteristic:
3	0.0 breakdown voltage, dc
С	urrent Rating Per Characteristic:
1	50.00 milliamperes source cutoff current preset
Ρ	ower Rating Per Characteristic:
2	00.0 milliwatts small-signal input power, common-collector absolute
M	aximum Operating Tempurature Per Measurement Point:
1	75.0 degrees celsius ambient air
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	helf Life:
N	/a
U	nit Of Measure:
D	emilitarization:
N	0
F	ig:
•	110a0